## NSN 5962-01-291-5019

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View Online at https://aerobasegroup.com/nsn/5962-01-291-5019 **Body Length:** Between 0.342 inches and 0.358 inches **Body Width:** Between 0.342 inches and 0.358 inches **Body Height:** Between 0.060 inches and 0.100 inches **Maximum Power Dissipation Rating:** 1.2 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and bipolar and programmable **Inclosure Material:** Ceramic **Inclosure Configuration:** Leaded chip carrier **Output Logic Form:** Bipolar metal-oxide semiconductor **Input Circuit Pattern:** 16 input **Case Outline Source And Designator:** C-2 mil-m-38510 **Current Rating Per Characteristic:** 12.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 7.0 volts power source **Memory Device Type:** Pal **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 20 pin Shelf Life: N/a **Unit Of Measure:** 

**Demilitarization:** 

Yes - demil/mli

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